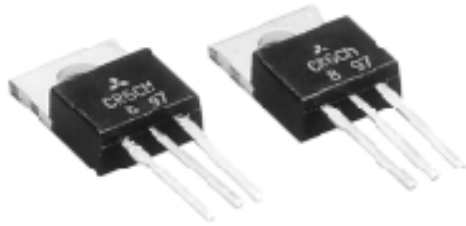


CR6CM

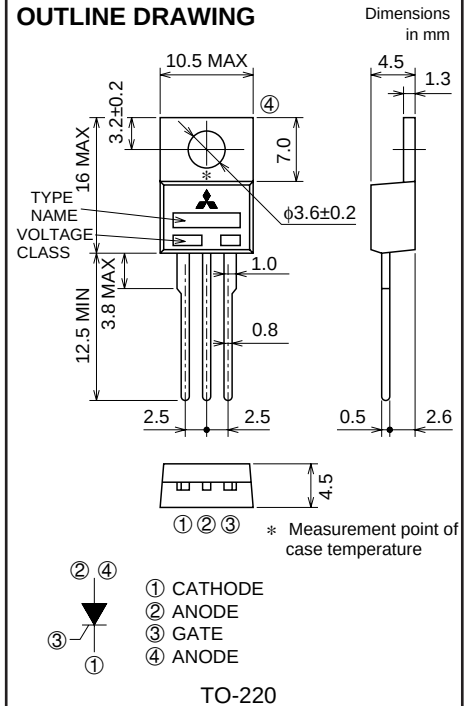
MEDIUM POWER USE
NON-INSULATED TYPE, GLASS PASSIVATION TYPE

CR6CM



- I_T (AV) 6A
- V_{DRM} 400V/600V
- I_{GT} 10mA

OUTLINE DRAWING



APPLICATION

Switching mode power supply, ECR, regulator for autocycle, motor control

MAXIMUM RATINGS

Symbol	Parameter	Voltage class		Unit
		8	12	
V_{RRM}	Repetitive peak reverse voltage	400	600	V
V_{RSM}	Non-repetitive peak reverse voltage	500	720	V
V_R (DC)	DC reverse voltage	320	480	V
V_{DRM}	Repetitive peak off-state voltage	400	600	V
V_D (DC)	DC off-state voltage	320	480	V

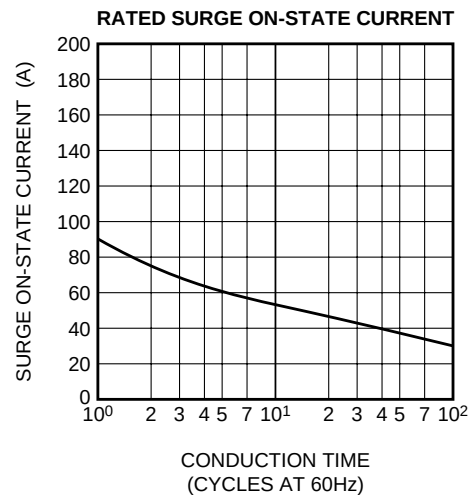
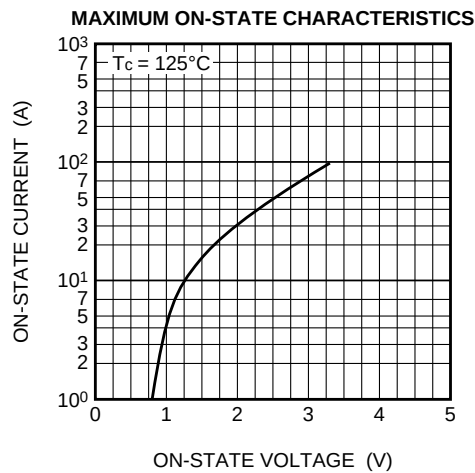
Symbol	Parameter	Conditions	Ratings	Unit
I_T (RMS)	RMS on-state current		9.4	A
I_T (AV)	Average on-state current	Commercial frequency, sine half wave, 180° conduction, $T_c=88^\circ\text{C}$	6	A
I_{TSM}	Surge on-state current	60Hz sine half wave 1 full cycle, peak value, non-repetitive	90	A
I^2_t	I^2_t for fusing	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current	34	A ² s
PGM	Peak gate power dissipation		5	W
PG (AV)	Average gate power dissipation		0.5	W
V_{FGM}	Peak gate forward voltage		6	V
V_{RGM}	Peak gate reverse voltage		10	V
I_{FGM}	Peak gate forward current		2	A
T_j	Junction temperature		-40 ~ +125	°C
T_{stg}	Storage temperature		-40 ~ +125	°C
—	Weight	Typical value	2.0	g

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
IRRM	Repetitive peak reverse current	T _J =125°C, V _{RRM} applied	—	—	2.0	mA
IDRM	Repetitive peak off-state current	T _J =125°C, V _{DRM} applied	—	—	2.0	mA
V _{TM}	On-state voltage	T _C =25°C, I _{TM} =20A, instantaneous value	—	—	1.7	V
V _{GT}	Gate trigger voltage	T _J =25°C, V _D =6V, I _T =1A	—	—	1.0	V
V _{GD}	Gate non-trigger voltage	T _J =125°C, V _D =1/2V _{DRM}	0.2	—	—	V
I _{GT}	Gate trigger current	T _J =25°C, V _D =6V, I _T =1A	—	—	10	mA
I _H	Holding current	T _J =25°C, V _D =12V	—	15	—	mA
R _{th(j-c)}	Thermal resistance	Junction to case *1	—	—	3.0	°C/W

*1. The contact thermal resistance R_{th(j-c)} is 1.0°C/W with greased.

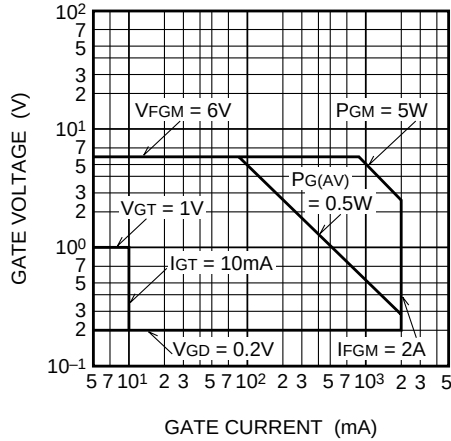
PERFORMANCE CURVES



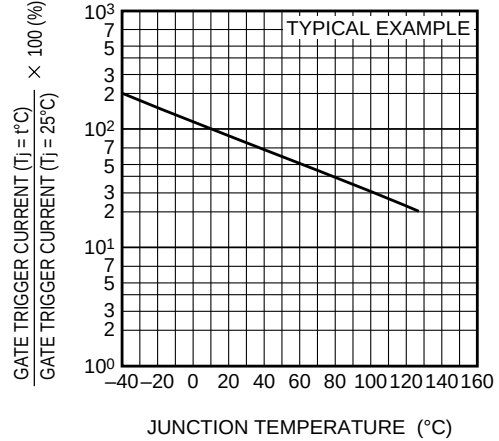
CR6CM

MEDIUM POWER USE
NON-INSULATED TYPE, GLASS PASSIVATION TYPE

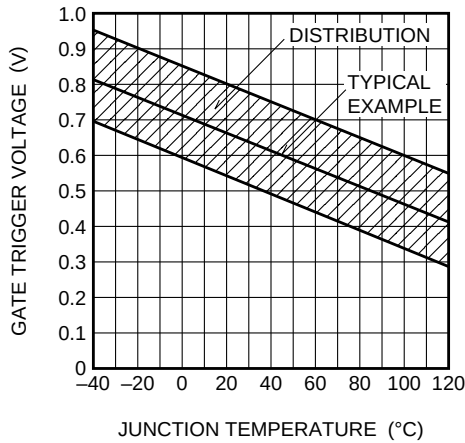
GATE CHARACTERISTICS



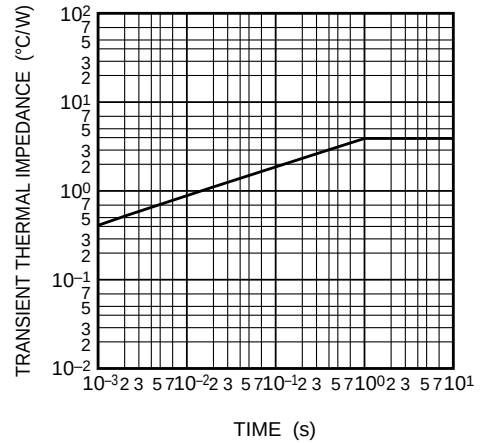
GATE TRIGGER CURRENT VS. JUNCTION TEMPERATURE



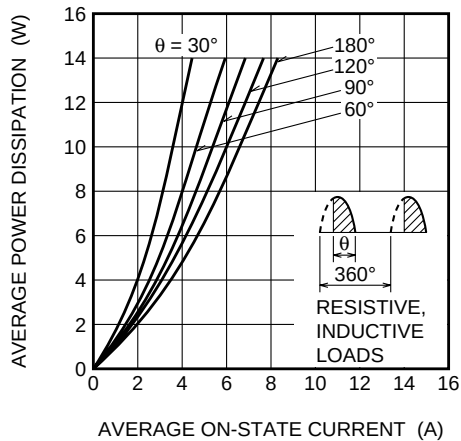
GATE TRIGGER VOLTAGE VS. JUNCTION TEMPERATURE



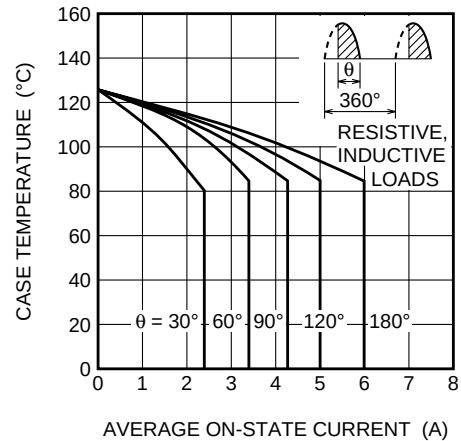
MAXIMUM TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (JUNCTION TO CASE)



MAXIMUM AVERAGE POWER DISSIPATION (SINGLE-PHASE HALF WAVE)



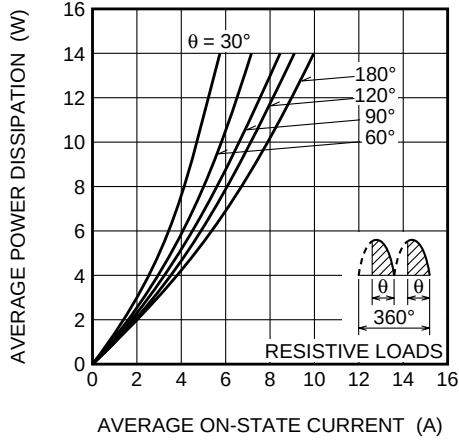
ALLOWABLE CASE TEMPERATURE VS. AVERAGE ON-STATE CURRENT (SINGLE-PHASE HALF WAVE)



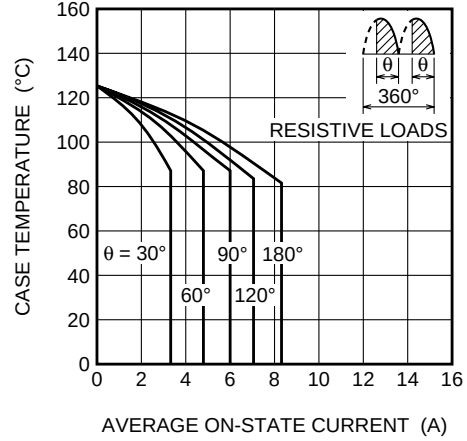
CR6CM

MEDIUM POWER USE
NON-INSULATED TYPE, GLASS PASSIVATION TYPE

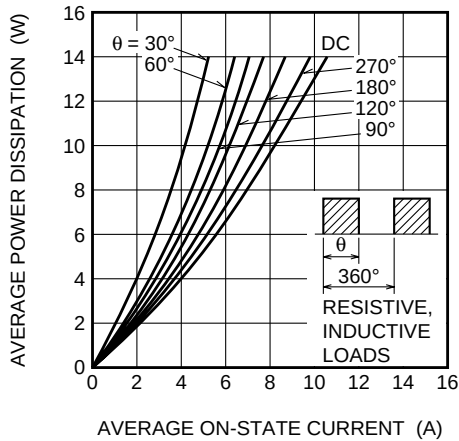
MAXIMUM AVERAGE POWER DISSIPATION
(SINGLE-PHASE FULL WAVE)



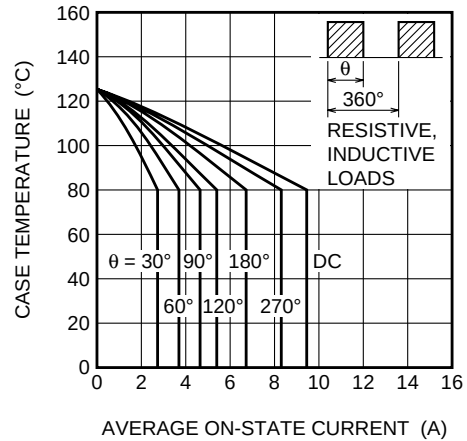
ALLOWABLE CASE TEMPERATURE VS.
AVERAGE ON-STATE CURRENT
(SINGLE-PHASE FULL WAVE)



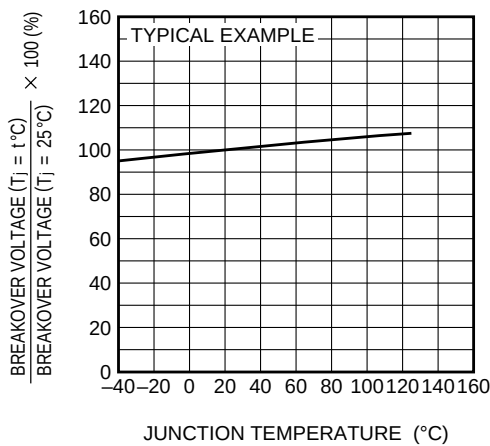
MAXIMUM AVERAGE POWER DISSIPATION
(RECTANGULAR WAVE)



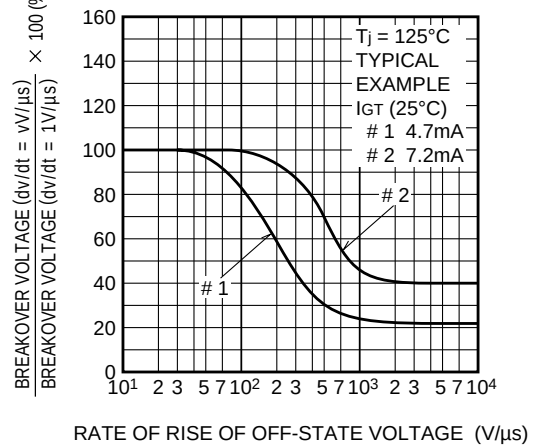
ALLOWABLE AMBIENT TEMPERATURE VS.
AVERAGE ON-STATE CURRENT
(RECTANGULAR WAVE)



BREAKOVER VOLTAGE VS.
JUNCTION TEMPERATURE



BREAKOVER VOLTAGE VS.
RATE OF RISE OF OFF-STATE VOLTAGE



CR6CM

MEDIUM POWER USE
NON-INSULATED TYPE, GLASS PASSIVATION TYPE

